



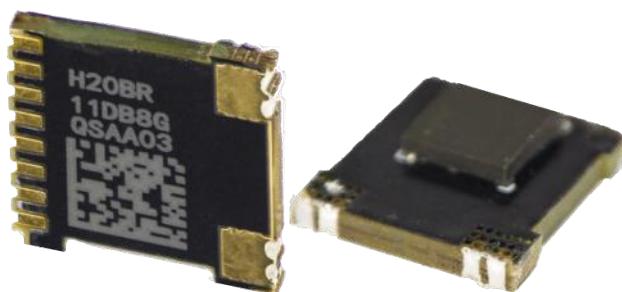
## Current Sensor

Product Series: STK-616H

Part number: STK-616H-20GB

STK-616H-30GB

Version: Ver5.1



Sinomags Technology Co., Ltd

Web site: [www.sinomags.com](http://www.sinomags.com)

## CONTENT

1.	Description .....	2
2.	Part number definition .....	3
3.	Temperature vs Current .....	3
4.	Functional Block Diagram .....	4
5.	Electrical data STK-616H-xxGB .....	5
6.	Dimension of STK-616H .....	6
7.	Pin definition for product .....	7
8.	PCB layout recommendation .....	7
9.	Frequency bandwidth .....	8
10.	Step response time .....	8
11.	Examples of OCD function .....	9
12.	General information on OCD .....	9

## 1. Description

The STK-616H series current sensor is based on TMR (tunnel magnetoresistance) technology and open-loop design. It is suitable for DC, AC pulsed and any kind of irregular current measurement under the isolated conditions.

### Typical applications

- AC Variable speed drives
- Inverter
- Electric welder power supply
- Switched model power supplies (SMPS)

### General parameter

Parameter	Symbol	Unit	Value
Working temperature	T_A	°C	-40 ~ 125
Storage temperature	Htg	°C	-40 ~ 125
Mass	m	g	1

### Absolute maximum rating

Parameter	Symbol	Unit	Value
Supply voltage	Vcc	V	6
ESD rating (HBM)	U_ESD	kV	4

Remark: the unrecoverable damage may occur when the product works on the conditions over the absolute maximum ratings. Long-time working on the absolute maximum ratings may cause the degradation on performance and reliability.

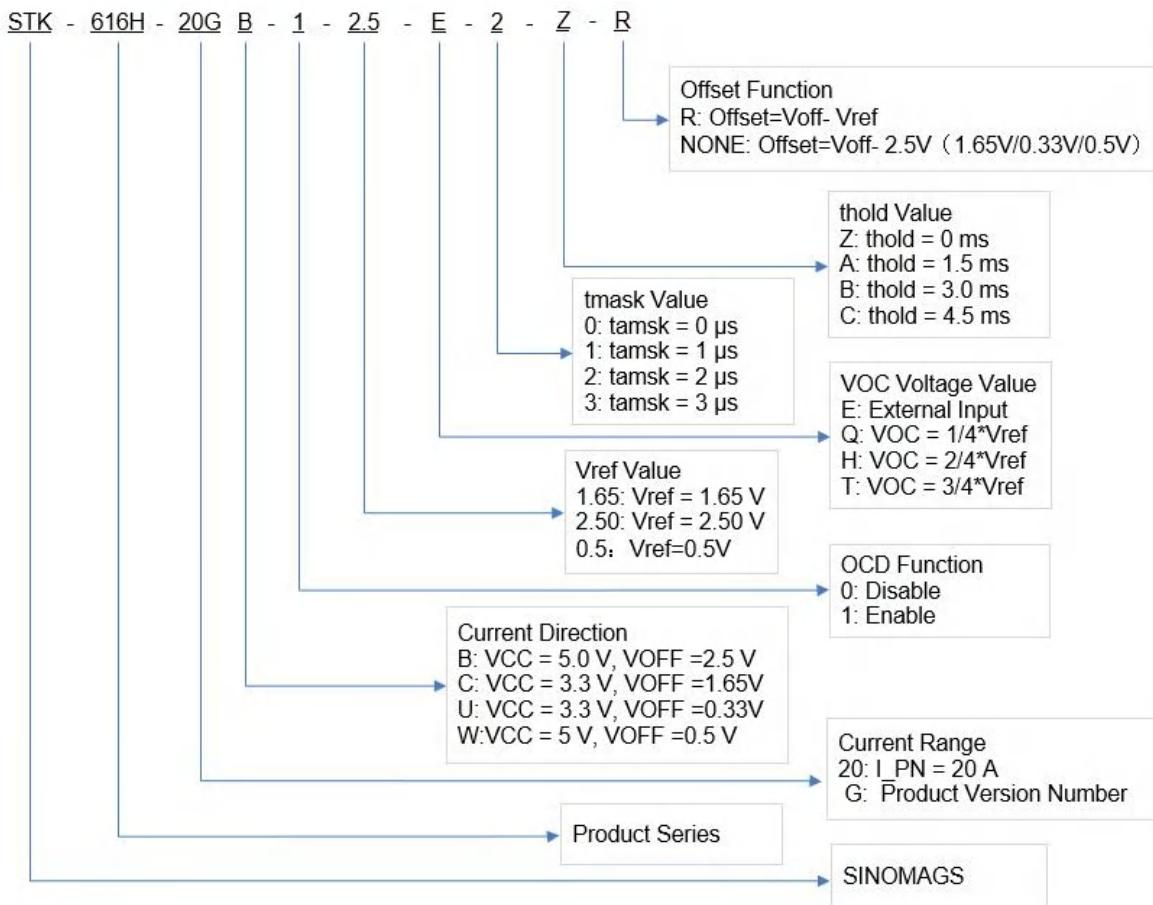
### Isolation parameter

Parameter	Symbol	Unit	Value	Comment
RMS voltage for AC test 50Hz/1 min	Ud	kV	2.4	
Impulse withstand voltage 1.2/50μs	Üw	kV	2.5	
Impulse current 8/20us	Iw	kA	15	
Clearance distance (pri. -sec)	dCl	mm	7	Determined by customer's layout
Creepage distance (pri. -sec)	dCp	mm	7	

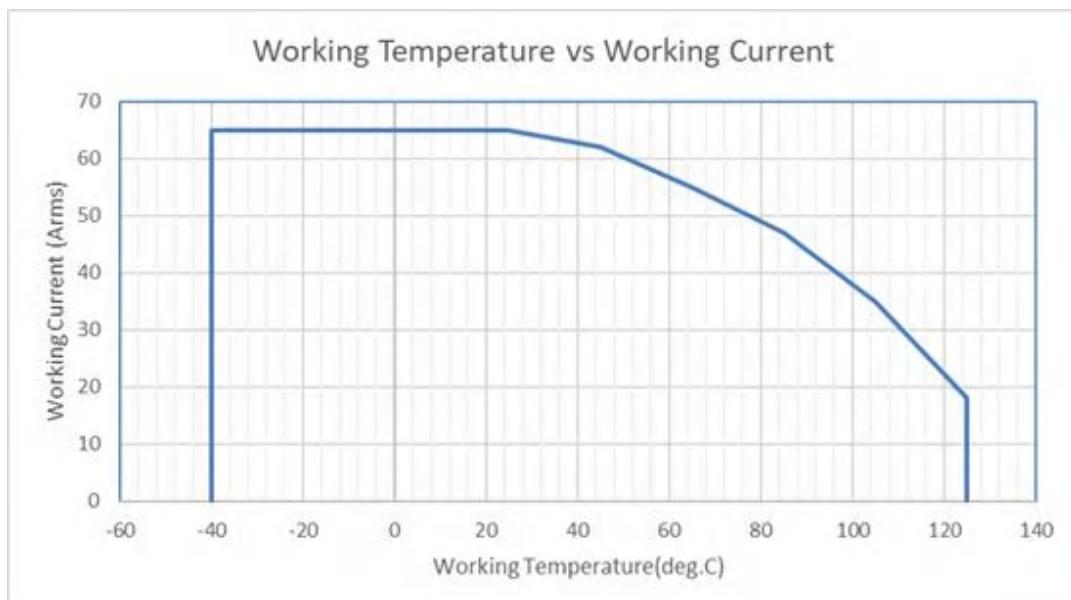
### Measuring current table

Product	Optimized Range I_pn (A)	Sensitivity, (mV/A)	T(°C)
STK-616H-20GB-1-2.5-E-2-Z-R	±20 A	40	-40 ~ 125
STK-616H-30GB-1-2.5-E-2-Z-R	±30 A	26.67	-40 ~ 125

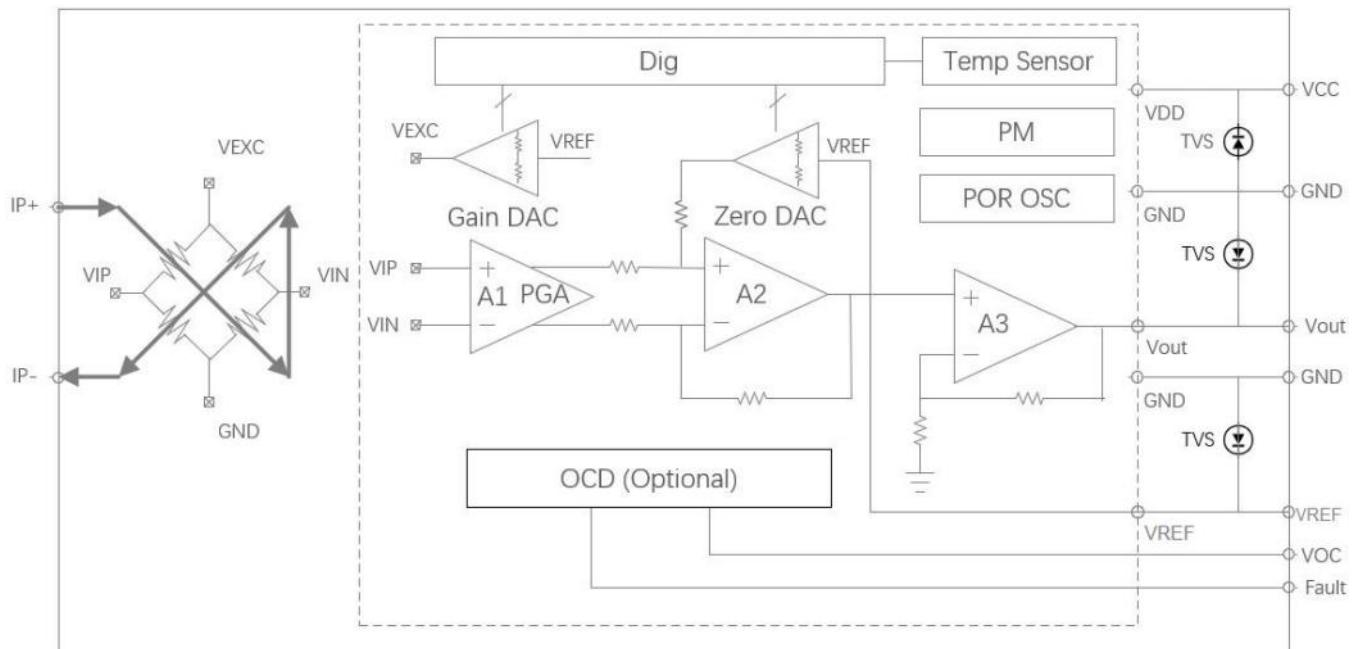
## 2. Part number definition



## 3. Temperature vs Current



## 4. Functional Block Diagram

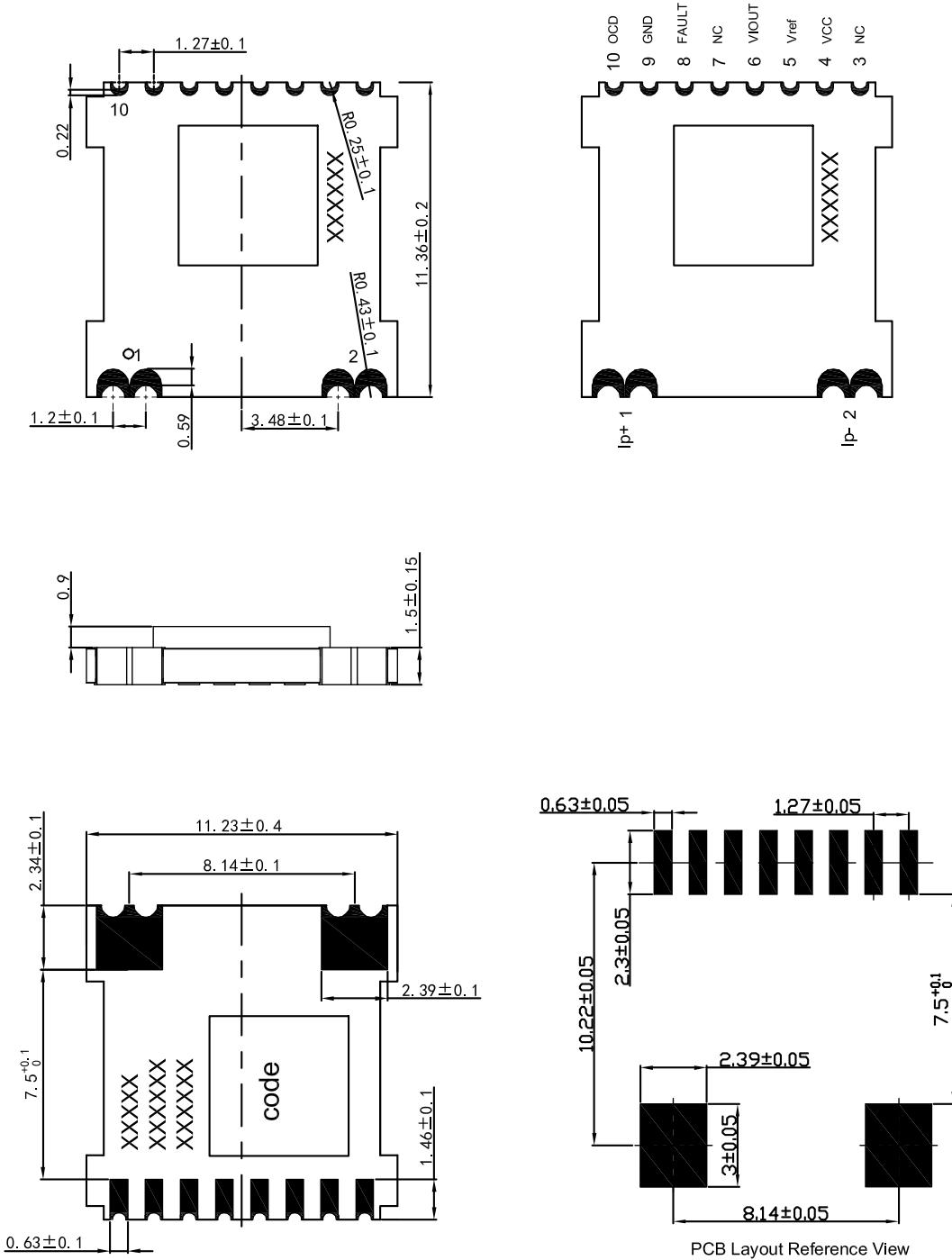


## 5. Electrical data STK-616H-xxGB

Condition:  $T_A = 25^\circ\text{C}$ ,  $V_{cc} = 5 \text{ V}$

Parameter	Symbol	Unit	Min	Typ	Max	Comment
General parameters						
Primary nominal current	$I_{pn}$	A	-20		20	STK-616H-20GB
			-30		30	STK-616H-30GB
Supply voltage	$V_{cc}$	V	4.5	5	5.5	
Current consumption	$I_{cc}$	mA		7	12	
Primary conductor resistance	$R_{IP}$	$\text{m}\Omega$		0.4		
Quiescent voltage@0A	$V_{off}$	V	2.45	2.5	2.55	
Reference voltage	$V_{ref}$	V	2.45	2.5	2.55	
Electrical offset voltage	Offset	mV		$\pm 10$		$V_{off} - V_{ref}$
Output Specifications	$R_{out}$	$\Omega$	1		30	
	$R_{ref}$		1		80	
Theoretical gain	$G_{th}$	mV/A		40		STK-616H-20GB
				26.67		STK-616H-30GB
OCD function (if applicable)						
OCD range	$V_{OC}$	V	0.5		3.3	
FOULT error		%		5%		% of OCD
OCD Hysteresis	$I_{HYS}$	%		10%		% of OCD
OCD Fault Mask	$t_{mask}$	$\mu\text{s}$		2		0, 1, 2, 3 $\mu\text{s}$
OCD Fault Mask error	$T_{mask\_error}$	ns		125		
OCD Fault Hold Time	$t_{hold}$	ms		0		0, 1.5, 3, 4.5 ms
Accuracy performance						
Rated linearity error@ $25^\circ\text{C}$	Non-L	$\% I_{pn}$		$\pm 1.5$		$\pm I_{pn}$
Step response time	$t_{res}$	$\mu\text{s}$		2		@90% of $I_{pn}$
Frequency bandwidth	BW	MHz		300		@-3dB
Output voltage noise	$V_{noise}$	mVpp		20		
Accuracy @ $25^\circ\text{C}$	X	$\% I_{pn}$		$\pm 1.5$		@ $0.5 * I_{pn}$
Thermal drift of $G_{th}$	$GAIN_T$	$\% G_{th}$		$\pm 1.5$		@ $-40 \sim 125^\circ\text{C}$
Thermal drift of $V_{off}$	$V_{off\_T}$	mV		$\pm 15$		drift related to the value @ $25^\circ\text{C}$
Total Accuracy	X_TRange	$\% I_{pn}$		$\pm 3$		

## 6. Dimension of STK-616H

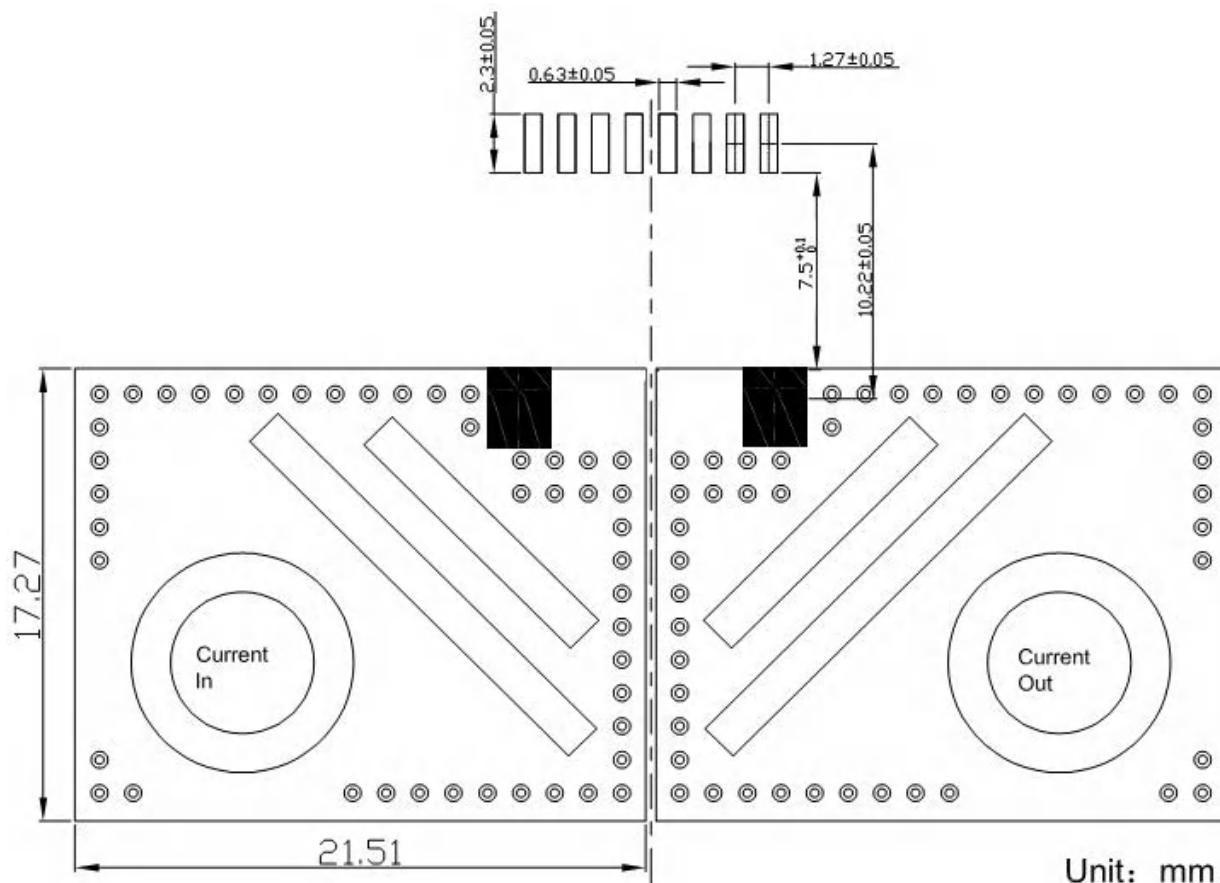


The mark of "H XXBN" on the top surface shows the information on the "Part number": "H" = "STK-616H", "XX" = "Product sensing range", "B" = "Current direction", "N" = Offset function.

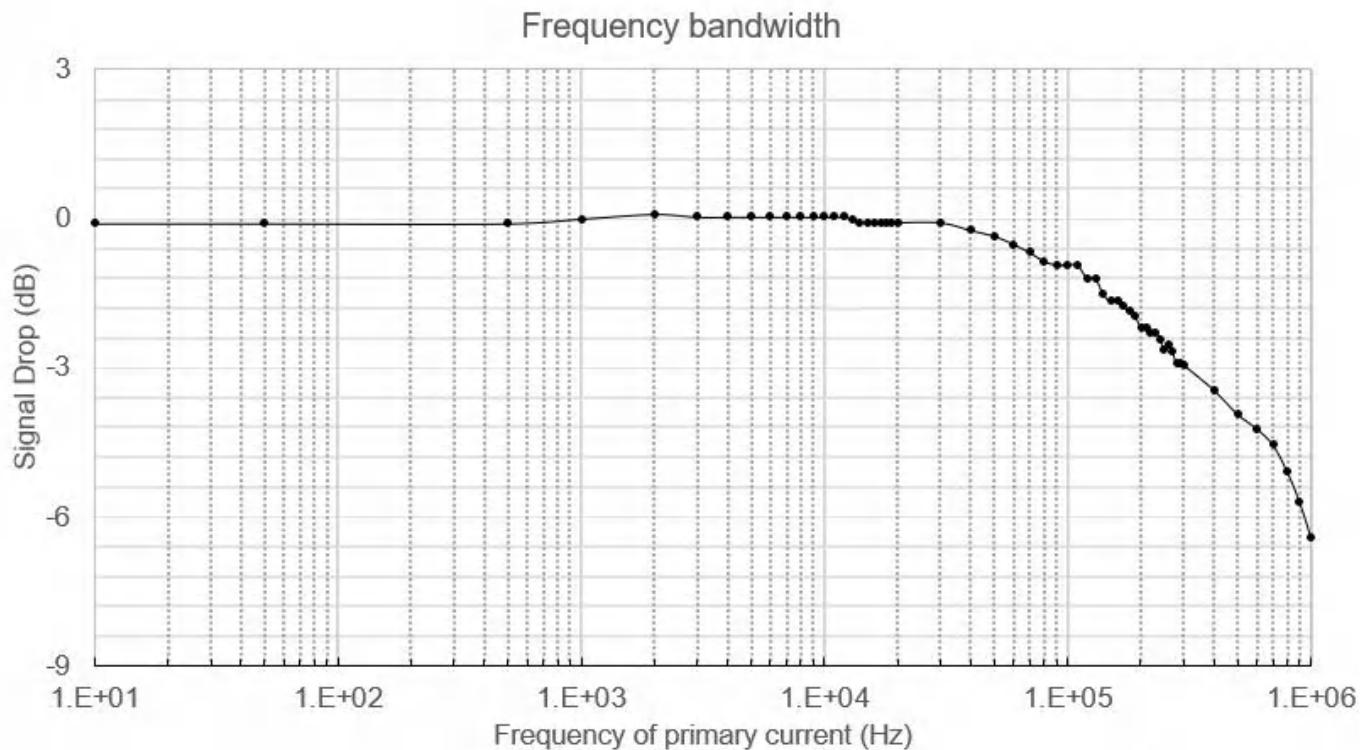
## 7. Pin definition for product

PIN	Symbol	Description
1	IP+	Primary conductor pin ( + )
2	IP-	Primary conductor pin ( - )
3	NC	NC
4	VCC	Power supply pin
5	Vref	Reference pin, output function
6	VOUT	Sensor output pin
7	NC	NC
8	Fault	Over current detection alarm output, the pin is open leakage output. Normally, the output of fault pin is high level.
9	GND	Ground terminal
10	OCD	Over current detection threshold input pin

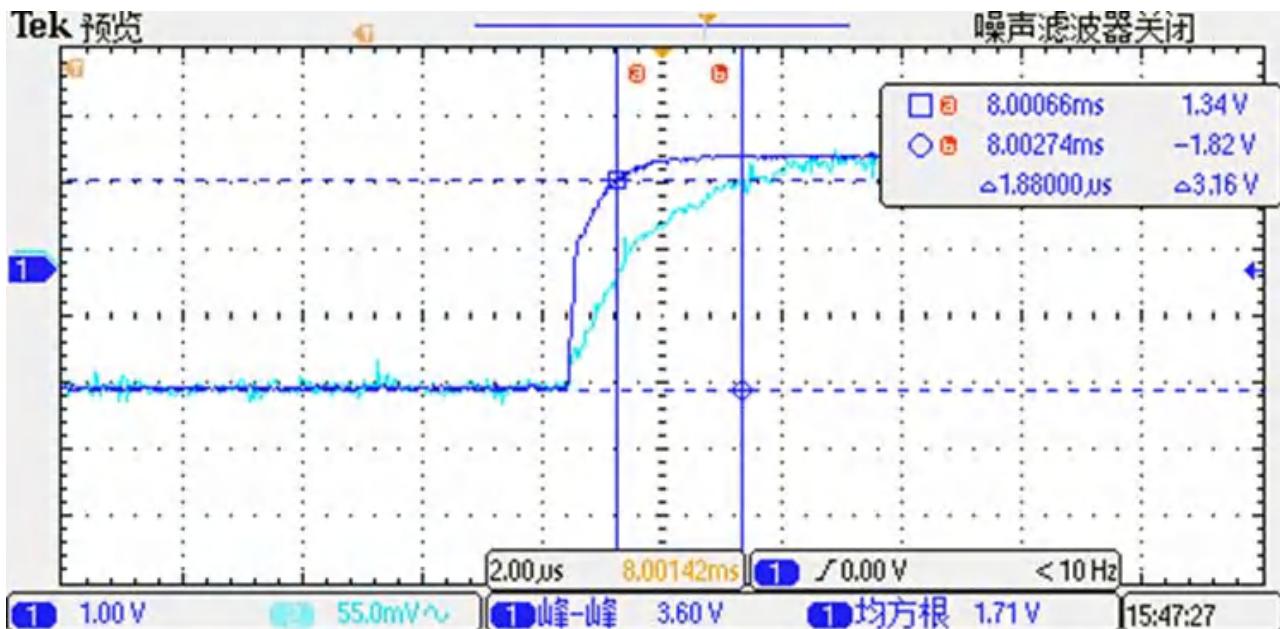
## 8. PCB layout recommendation



## 9. Frequency bandwidth

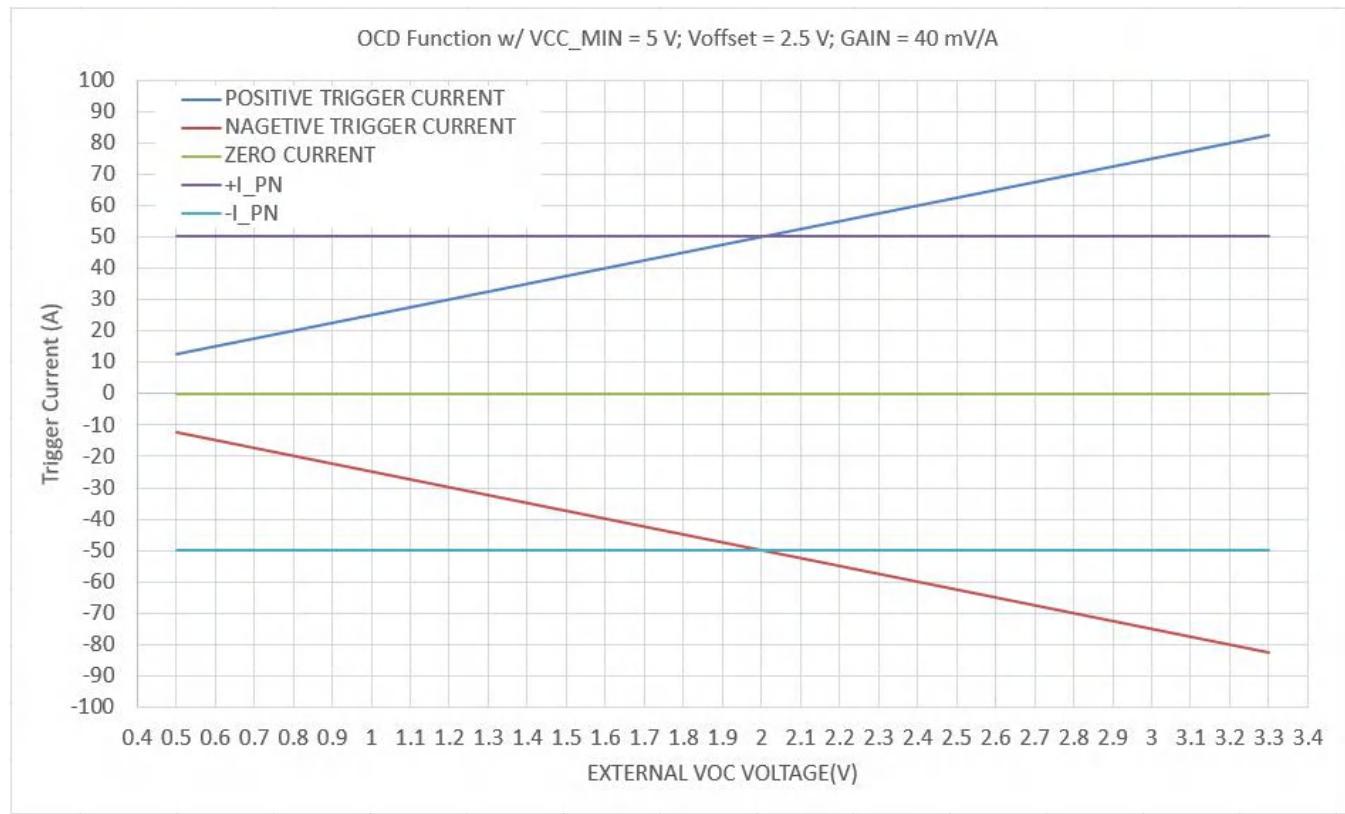


## 10. Step response time



The typical frequency response of STK-616H current sensor. The response time from 90% of the primary current (blue) to 90% of the secondary output (green) is 2μs.

## 11.Examples of OCD function



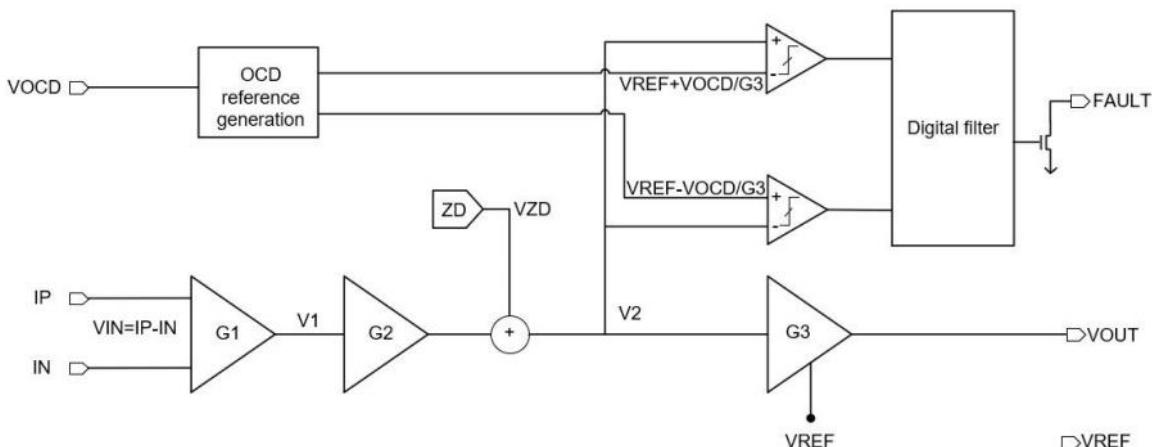
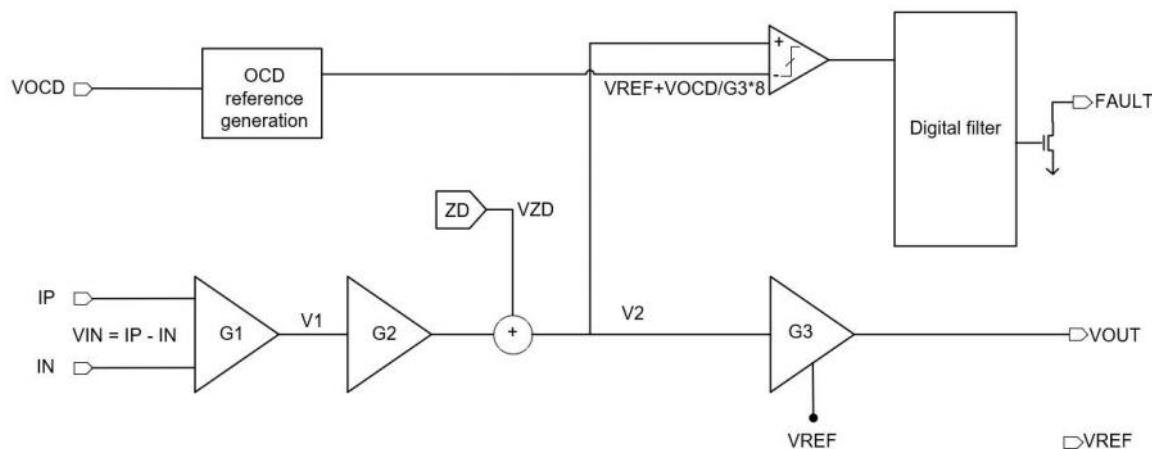
OCD function for STK-616H-20GB

## 12.General information on OCD

This section describes the general information on OCD function, the specific functions, which are not listed in the section of “electrical data”, can be defined per request.

Since the trigger voltage is set after the second amplifier, the OCD function supports that the trigger current can be higher than  $I_{pn}$ . The trigger voltage can be defined:

- a)  $V_{ref} = 2.5 \text{ V}$ 
  - ①.  $0.5 \text{ V} \leq \text{VOC} \leq \text{Vcc} - 1.7 \text{ V};$
  - ②. Trigger voltage =  $V_{ref} \pm \text{VOC};$
  - ③. Trigger current =  $(V_{ref} \pm \text{VOC} - \text{Voff}) / G_{th};$
- b)  $V_{ref} = 1.65 \text{ V}$ 
  - ①.  $0.3 \text{ V} \leq \text{VOC} \leq \text{Vcc} - 1.7 \text{ V};$
  - ②. Trigger voltage =  $V_{ref} \pm \text{VOC};$
  - ③. Trigger current =  $(V_{ref} \pm \text{VOC} - \text{Voff}) / G_{th}$
- c)  $V_{ref} = 0.5 \text{ V}$ 
  - ①.  $0.2 \text{ V} \leq \text{VOC} \leq 0.5 \text{ V};$
  - ②. Trigger voltage =  $V_{ref} + 8 * \text{VOC};$
  - ③. Trigger current =  $(V_{ref} + \text{VOC} - \text{Voff}) / G_{th}$


 Functional Block Diagram on OCD function when  $V_{ref} = 2.5 \text{ V}$ 

 Functional Block Diagram on OCD function when  $V_{ref} = 0.5 \text{ V}$ 

With the above definition, below shows the relationship between trigger voltage and the setting of Vcc, VOC.

